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Approved for use through 10/31/2002. OMB 0651-0031

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**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**

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Complete if Known

Sheet	1	of	4	Application Number	09/879,090
				Filing Date	June 13, 2001
				First Named Inventor	Satoshi YOSHIMOTO
				Group Art Unit	2814
				Examiner Name	H. Trinh
				Attorney Docket Number	0756-2326

U.S. PATENT DOCUMENTS

Examiner Initials ¹	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code ² (if known)			
WZ		6,492,659		Yamazaki et al.	12/10/2002	
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		Office ³	Number ⁴	Kind Code ² (if known)				
WZ		JP	06-005862			01/14/1994		Abst.
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		JP	08-228006			09/03/1996		Abst.

OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS

Examiner Initials ¹	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
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		Helen et al., <i>Reproducible High Field Effect Mobility Polysilicon Thin Film Transistors Involving Pulsed Nd:YVO₄ Laser Crystallization</i> , IEDM 99, Pages 297-300.	
		Inui et al., <i>Thresholdless Antiferroelectricity in Liquid Crystals and its Application to Displays</i> , J. Mater. Chem., Vol. 6, No. 4, Pages 671-673, January 1, 1996.	
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Examiner Signature	<i>H. Trinh</i>	Date Considered	5/16/25
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		Number	Kind Code ² (if known)			
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		Office ³	Number ⁴	Kind Code ⁵ (if known)				
[Signature]		JP	09-186336			07/15/1997		Full
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Examiner Signature	<i>Vicki Trinh</i>	Date Considered	5/18/05
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Application Number	09/879,090
Filing Date	June 13, 2001
First Named Inventor	Satoshi YOSHIMOTO
Group Art Unit	2814
Examiner Name	H. Trinh
Attorney Docket Number	0756-2326

U.S. PATENT DOCUMENTS

Examiner Initials ¹	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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Examiner
Signature*[Handwritten Signature]*

Date

Considered

05/16/05

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Substitute for form 1449A/PTO		Complete if Known	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)		Application Number	09/879,090
		Filing Date	June 13, 2001
		First Named Inventor	Satoshi YOSHIMOTO
		Group Art Unit	2814
		Examiner Name	H. Trinh
Page 1 of 4	4	of	4
		Attorney Docket Number	0756-2326

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Examiner Initials ¹	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY
		Number	Kind Code ² (if known)		
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Examiner Signature	<i>H. Trinh</i>	Date Considered	05/16/05
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Form PTO-1449
(Rev. 8-83)U.S. Department of Commerce
Patent and Trademark Office

Atty Docket 0756-2326

Serial No. 09/879,090

INFORMATION DISCLOSURE STATEMENT

JUL 31 2001

Applicants: Satoshi YOSHIMOTO

Filing Date: June 13, 2001

Group Art Unit:
Unassigned

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Examiner Initial	Document Number	Date	Name	Class	Subclass	Filing Date (if appropriate)
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Examiner *V. M. Turk* Date Considered *05/17/05*

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07/26/2001

Form PTO-1449 (Rev. 8-83)		U.S. Department of Commerce Patent and Trademark Office		Atty Docket 0756-2326	Serial No. 09/879,090
INFORMATION DISCLOSURE STATEMENT				Applicants: Satoshi YOSHIMOTO	
				Filing Date: June 13, 2001	Group Art Unit: Unassigned
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)					
Examiner Initial					
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